Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Overall Length:

Between 0.125 inches and 0.160 inches

Terminal Length:

Between 0.800 inches and 1.300 inches

Overall Diameter:

Between 0.060 inches and 0.085 inches

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

12.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter torr

Voltage Tolerance In Percent:

-5.0/+5.0

Current Rating Per Characteristic:

21.00 milliamperes voltage regulator diode current

Power Rating Per Characteristic:

1.5 watts total power dissipation

Maximum Operating Tempurature Per Measurement Point:

175.0 inlet swivel degrees fahrenheit

Test Data Document:

81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.